

500 mW Metallurgically Bonded Glass Surface Mount Zener Diodes

1N4614UR-1–1N4627UR-1e3
1N4099UR-1–1N4135UR-1e3



Product Overview

The 1N4099UR-1 through 1N4135UR-1 and 1N4614UR-1 through 1N4627UR-1 series are 500 mW, Zener voltage regulators in the surface mount, glass DO-213AA package. Voltages from 1.8 to 100V in 5%, 2% and 1% tolerances are available. They are constructed with an internal metallurgical bond and are mil-qualified up to the JANS level for high reliability applications.

Features

- Surface mount equivalent to JEDEC registered 1N4099 through 1N4135 and 1N4614 through 1N4627 series
- Internal metallurgical bond
- Max noise density 40 $\mu\text{V}/\sqrt{\text{Hz}}$ for 6.8V and up. Falls quickly to 1 $\mu\text{V}/\sqrt{\text{Hz}}$ at lower voltages.
- JAN, JANTX, JANTXV and JANS qualifications are available per MIL-PRF-19500/435
- This series is also available commercially with the CDLL prefix (CDLL4099-1–CDLL4135-1 and CDLL4614-1–CDLL4627-1). This CDLL prefix also replaces the MLL prefix on prior devices.
- RoHS compliant versions available (commercial grade only)

Figure 1. DO-213AA Package



Also available in: **DO-35 Package** (axial-leaded) and **DO-216 Package** (tabbed surface mount)

Applications/Benefits

- Regulates voltage over broad ranges of current and temperature.
- Extensive selection from 1.8 to 100 volts.
- Voltage tolerances of $\pm 5\%$ (standard), $\pm 2\%$ and $\pm 1\%$ are available.
- Hermetically sealed surface mount package.
- Non-sensitive to ESD per MIL-STD-750 method 1020.
- Minimal capacitance (see [Figure 4-3](#)).
- Inherently radiation hard as described in [MicroNote 050](#).

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1. Maximum Ratings

Table 1-1. Maximum Ratings at $T_C = +25\text{ }^{\circ}\text{C}$ Unless Otherwise Specified

Parameters/Test Conditions	Symbol	Value	Unit
Junction and Storage Temperature	T_J and T_{STG}	-65 to +175	$^{\circ}\text{C}$
Thermal Resistance Junction-to-Ambient ¹	$R_{\theta JA}$	300	$^{\circ}\text{C}/\text{W}$
Thermal Resistance Junction-to-End Cap	$R_{\theta JEC}$	100	$^{\circ}\text{C}/\text{W}$
Rated Average Power Dissipation ²	$P_{M(AV)}$	0.5	W
Forward Voltage at 200 mA	V_F	1.1	V
Solder Temperature at 10 s	—	260	$^{\circ}\text{C}$

Notes:

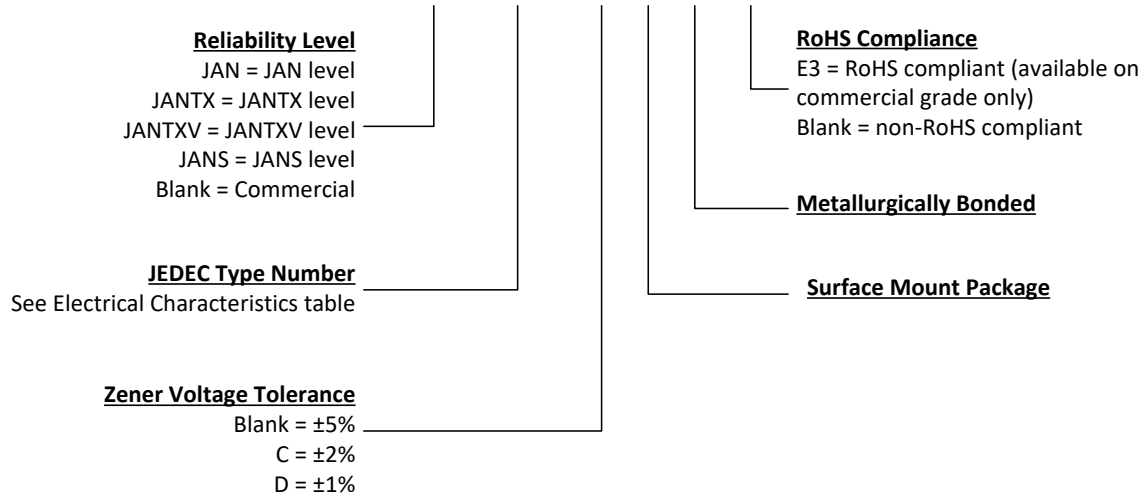
- When mounted on FR4 PC board (1 oz Cu) with recommended footprint (see [Pad Layout](#)).
- The 0.5 W linearly derates starting at $T_{EC} = 125\text{ }^{\circ}\text{C}$ and goes to zero at $175\text{ }^{\circ}\text{C}$. For ambient T_A condition on a typical PC board, it linearly derates from 500 mW starting at $25\text{ }^{\circ}\text{C}$ and goes to zero at $175\text{ }^{\circ}\text{C}$ (see [Figure 4-2](#)).

1.1. Mechanical and Packaging

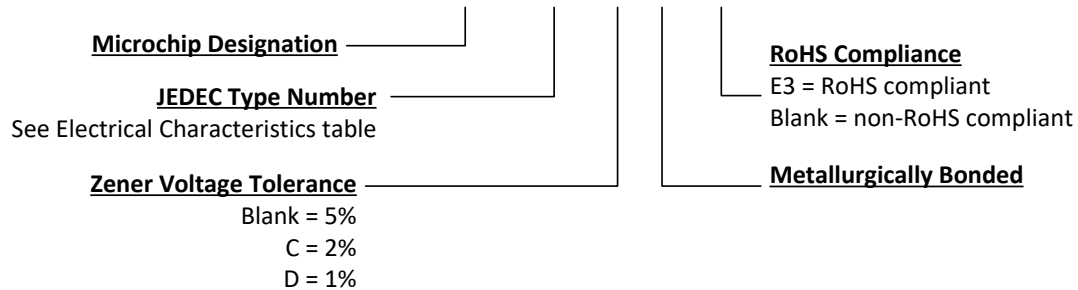
- Case: Hermetically sealed glass DO-213AA (SOD80 or CDLL34) MELF style package.
- Terminals: Tin-lead or RoHS compliant annealed matte-tin (on commercial grade only plating. Solderable per MIL-STD-750, method 2026.
- Polarity: Cathode indicated by banded end. Diode is to be operated with the banded end positive with respect to the opposite end for Zener regulation.
- Marking: Cathode band only.
- Tape and Reel option: Standard per EIA-481-1-A with 12 mm tape (add "TR" suffix to part number). Consult factory for quantities.
- Weight: Approximately 0.04 grams.
- See [Package Dimensions](#).

2. Part Nomenclature

JAN 1N4099 C UR -1 (e3)



CDLL 4099 C -1 (e3)



2.1. Symbols and Definitions

Table 2-1. Symbols and Definitions

Symbol	Definition
α_{VZ}	Temperature Coefficient of Regulator Voltage: The change in regulator voltage divided by the change in temperature that caused it expressed in %/C or mV/°C.
I_R	Reverse Current: The maximum reverse (leakage) current that will flow at the specified voltage and temperature.
I_Z, I_{ZT}, I_{ZK}	Regulator Current: The dc regulator current (I_Z), at a specified test point (I_{ZT}), new breakdown knee (I_{ZK}).
I_{ZM}	Maximum Regulator (Zener) Current: The maximum rated dc current for the specified power rating.
N_D	Noise Density: The noise generated over a specified frequency bandwidth usually specified in terms of $\mu V/\sqrt{Hz}$.
V_R	Reverse Voltage: The reverse voltage dc value, no alternating component.
V_Z	Zener Voltage: The Zener voltage the device will exhibit at a specified current (I_Z) in its breakdown region.
Z_{ZT} or Z_{ZK}	Dynamic Impedance: The small signal impedance of the diode when biased to operate in its breakdown region at a specified rms current modulation (typically 10% of I_{ZT} or I_{ZK}) and superimposed on I_{ZT} or I_{ZK} respectively.

3. Electrical Characteristics

Table 3-1. Electrical Characteristics at 25 °C Unless Otherwise Stated

Industry Part Number ¹	Microchip Part Number ¹	Nominal Zener Voltage V_Z at I_{ZT} ²	Zener Test Current I_{ZT}	Maximum Zener Impedance Z_{ZT} ³	Maximum Reverse Current I_R at V_R		Maximum Noise Density N_D at I_{ZT}	Maximum Zener Current I_{ZM}	Maximum Temp. Coeff. of Zener Voltage α_{VZ}
		Volts	μA	Ohms	μA	Volts	$\mu V/\sqrt{Hz}$	mA	%/°C
1N4614UR-1	CDLL4614-1	1.8	250	1200	3.5	1.0	1	120.0	-0.075
1N4615UR-1	CDLL4615-1	2.0	250	1250	2.5	1.0	1	110.0	-0.075
1N4616UR-1	CDLL4616-1	2.2	250	1300	2.0	1.0	1	100.0	-0.075
1N4617UR-1	CDLL4617-1	2.4	250	1400	1.0	1.0	1	95.0	-0.075
1N4618UR-1	CDLL4618-1	2.7	250	1500	0.5	1.0	1	90.0	-0.075
1N4619UR-1	CDLL4619-1	3.0	250	1600	0.4	1.0	1	87.0	-0.075
1N4620UR-1	CDLL4620-1	3.3	250	1650	3.5	1.5	1	85.0	-0.075
1N4621UR-1	CDLL4621-1	3.6	250	1700	3.5	2.0	1	83.0	-0.065
1N4622UR-1	CDLL4622-1	3.9	250	1650	2.5	2.0	1	80.0	-0.060
1N4623UR-1	CDLL4623-1	4.3	250	1600	2.0	2.0	1	77.0	-0.050
1N4624UR-1	CDLL4624-1	4.7	250	1550	5.0	3.0	1	75.0	-0.050, +0.020
1N4625UR-1	CDLL4625-1	5.1	250	1500	5.0	3.0	2	70.0	-0.045, +0.030
1N4626UR-1	CDLL4626-1	5.6	250	1400	5.0	4.0	4	65.0	-0.020, +0.040
1N4627UR-1	CDLL4627-1	6.2	250	1200	5.0	5.0	5	61.0	-0.010, +0.050
1N4099UR-1	CDLL4099-1	6.8	250	200	1.0	5.2	40	56.0	+0.060
1N4100UR-1	CDLL4100-1	7.5	250	200	1.0	5.7	40	51.0	+0.065
1N4101UR-1	CDLL4101-1	8.2	250	200	0.5	6.3	40	46.0	+0.070
1N4102UR-1	CDLL4102-1	8.7	250	200	0.5	6.7	40	44.0	+0.075
1N4103UR-1	CDLL4103-1	9.1	250	200	0.5	7.0	40	42.0	+0.080
1N4104UR-1	CDLL4104-1	10.0	250	200	0.5	7.6	40	38.0	+0.080
1N4105UR-1	CDLL4105-1	11.0	250	200	0.05	8.5	40	35.0	+0.080
1N4106UR-1	CDLL4106-1	12.0	250	200	0.05	9.2	40	32.0	+0.080
1N4107UR-1	CDLL4107-1	13.0	250	200	0.05	9.9	40	29.0	+0.080
1N4108UR-1	CDLL4108-1	14.0	250	200	0.05	10.7	40	27.0	+0.085
1N4109UR-1	CDLL4109-1	15.0	250	100	0.05	11.4	40	25.0	+0.085
1N4110UR-1	CDLL4110-1	16.0	250	100	0.05	12.2	40	24.0	+0.085
1N4111UR-1	CDLL4111-1	17.0	250	100	0.05	13.0	40	22.0	+0.090
1N4122UR-1	CDLL4112-1	18.0	250	100	0.05	13.7	40	21.0	+0.090
1N4113UR-1	CDLL4113-1	19.0	250	150	0.05	14.5	40	20.0	+0.090
1N4114UR-1	CDLL4114-1	20.0	250	150	0.01	15.2	40	19.0	+0.090
1N4115UR-1	CDLL4115-1	22.0	250	150	0.01	16.8	40	17.0	+0.090
1N4116UR-1	CDLL4116-1	24.0	250	150	0.01	18.3	40	16.0	+0.090
1N4117UR-1	CDLL4117-1	25.0	250	150	0.01	19.0	40	15.0	+0.090
1N4118UR-1	CDLL4118-1	27.0	250	150	0.01	20.5	40	14.0	+0.090
1N1449UR-1	CDLL4119-1	28.0	250	200	0.01	21.3	40	14.0	+0.095
1N4120UR-1	CDLL4120-1	30.0	250	200	0.01	22.8	40	13.0	+0.095
1N412UR-1	CDLL4121-1	33.0	250	200	0.01	25.1	40	12.0	+0.095
1N4122UR-1	CDLL4122-1	36.0	250	200	0.01	27.4	40	11.0	+0.095
1N4123UR-1	CDLL4123-1	39.0	250	200	0.01	29.7	40	9.8	+0.095

Table 3-1. Electrical Characteristics at 25 °C Unless Otherwise Stated (continued)

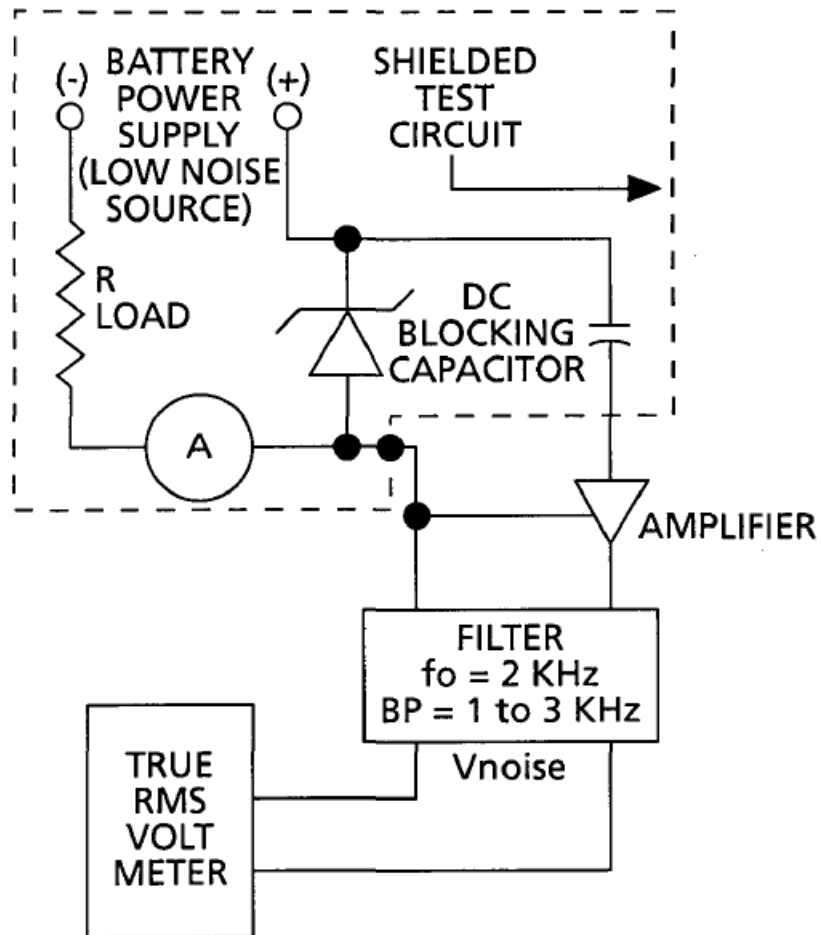
Industry Part Number ¹	Microchip Part Number ¹	Nominal Zener Voltage V_Z at I_{ZT} ²	Zener Test Current I_{ZT}	Maximum Zener Impedance Z_{ZT} ³	Maximum Reverse Current I_R at V_R		Maximum Noise Density N_D at I_{ZT}	Maximum Zener Current I_{ZM}	Maximum Temp. Coeff. of Zener Voltage α_{VZ}
		Volts	μA	Ohms	μA	Volts	$\mu V/\sqrt{Hz}$	mA	%/°C
1N4124UR-1	CDLL4124-1	43.0	250	250	0.01	23.7	40	8.9	+0.095
1N4125UR-1	CDLL4125-1	47.0	250	250	0.01	35.8	40	8.1	+0.095
1N4126UR-1	CDLL4126-1	51.0	250	300	0.01	38.8	40	7.5	+0.100
1N4127UR-1	CDLL4127-1	56.0	250	300	0.01	42.6	40	6.7	+0.100
1N4128UR-1	CDLL4128-1	60.0	250	400	0.01	45.6	40	6.4	+0.100
1N4129UR-1	CDLL4129-1	62.0	250	500	0.01	47.1	40	6.1	+0.100
1N4130UR-1	CDLL4130-1	68.0	250	700	0.01	51.7	40	5.6	+0.100
1N4131UR-1	CDLL4131-1	75.0	250	700	0.01	57.0	40	5.1	+0.100
1N4132UR-1	CDLL4132-1	82.0	250	800	0.01	62.4	40	4.6	+0.100
1N4133UR-1	CDLL4133-1	87.0	250	1000	0.01	66.2	40	4.4	+0.100
1N4134UR-1	CDLL4134-1	91.0	250	1200	0.01	69.2	40	4.2	+0.100
1N4135UR-1	CDLL4135-1	100.0	250	1600	0.01	76.0	40	3.8	+0.100

Notes:

1. These may be ordered as either 1N4614UR-1 through 1N4099UR-1 or CDLL4614-1 through CDLL4627-1 and CDLL4099-1 through CDLL4135-1. For 1N military types, add the JAN, JANTX or JANTXV prefix for required screening to the industry part number.
2. The JEDEC type numbers shown above have a standard tolerance of $\pm 5\%$ on the nominal Zener voltage. V_Z is measured with the diode in thermal equilibrium (still air) at 25 °C for end-cap terminations.
3. Zener impedance is derived by superimposing on I_{ZT} a 60 Hz rms ac current at 10% of I_{ZT} . See MicroNote 202 for Z_{ZT} variation with I_Z .

4. Graphs

Figure 4-1. Noise Density Measurement Circuit



Noise density, (N_D) is specified in microvolt-rms per square-root-hertz. Actual measurement is performed using a 1 KHz to 3 KHz frequency bandpass filter at a constant Zener test current (I_{ZT}) at 25 °C ambient temperature. N_D is calculated from the formula.

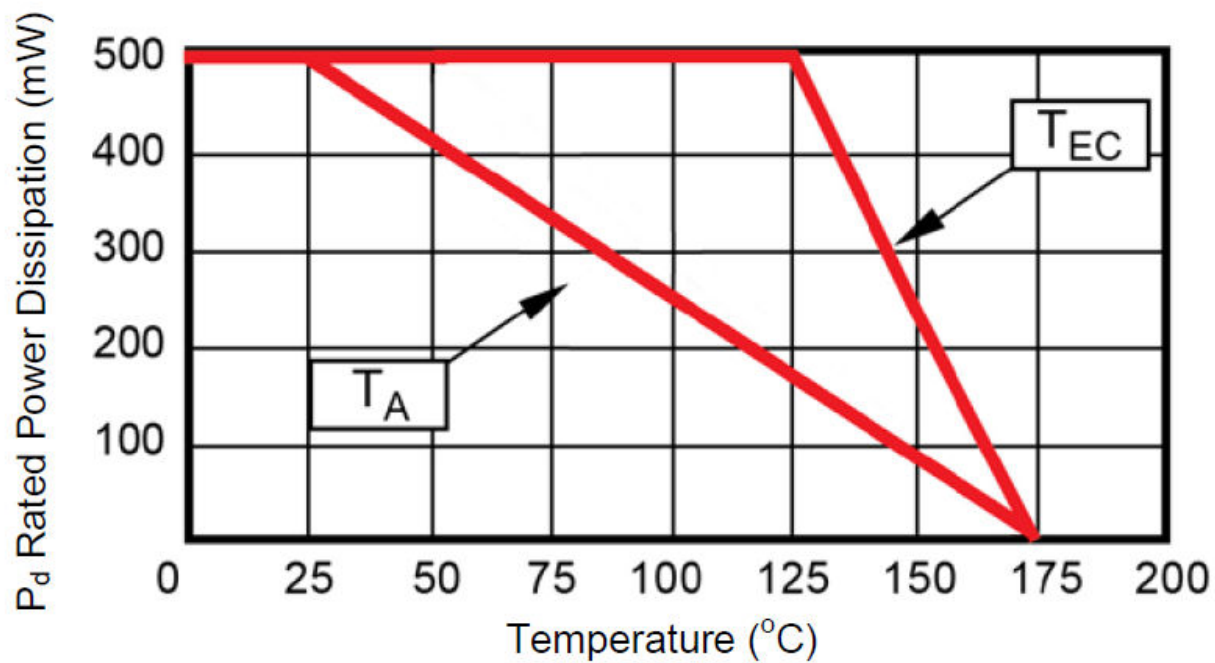
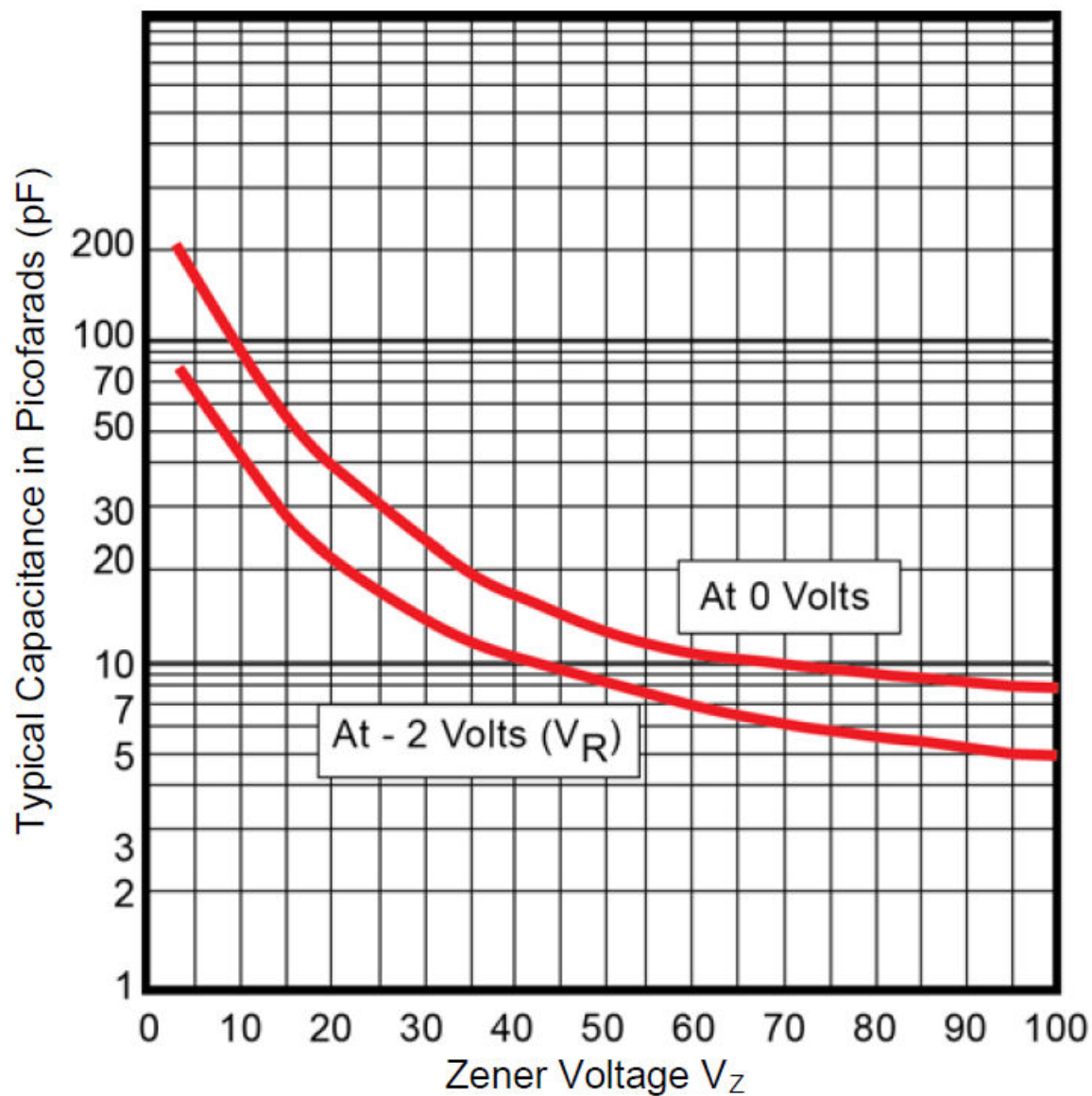
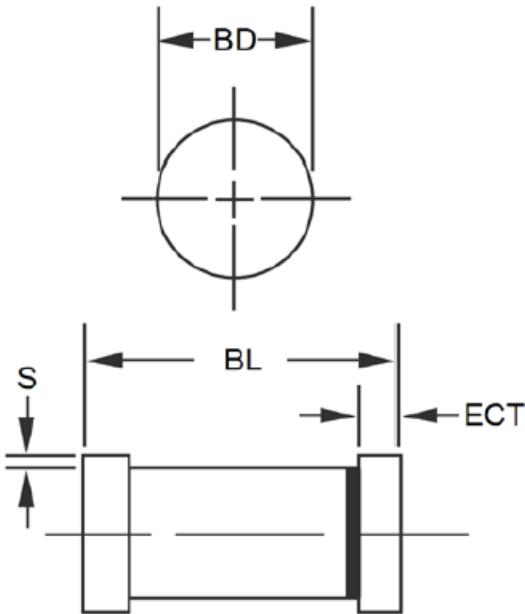
Figure 4-2. Power Derating Curve

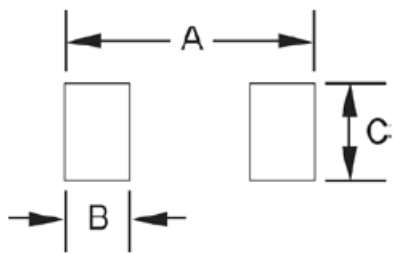
Figure 4-3. Capacitance vs. Zener Voltage (Typical)

5. Package Dimensions



Dim	Inch		Millimeters	
	Min	Max	Min	Max
BD	0.063	0.067	1.60	1.70
BL	0.130	0.146	3.30	3.71
ECT	0.016	0.022	0.41	0.56
S	0.001 min		0.03 min	

6. Pad Layout



	Inch	Millimeter
A	0.200	5.08
B	0.055	1.40
	0.080	2.03

7. Revision History

Revision	Date	Description
A	10/2025	Initial version

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